



Data Sheet No. 911012A

November 1991

## Single-Phase Diode Rectifier Bridge

### FEATURES:

- Avalanche Rated Parts Available
- Isolated Direct Copper Bond Base Plate
- Easy Chassis Mounting
- 1/4" Fast-On Connectors
- Blocking Voltage to 1600 Volts
- UL Registered (E72873M)

### APPLICATIONS:

- Power Supplies
- Input Rectifiers for Variable Frequency
- Rectifiers for DC Motor Field Current

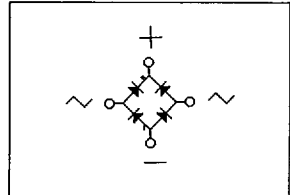
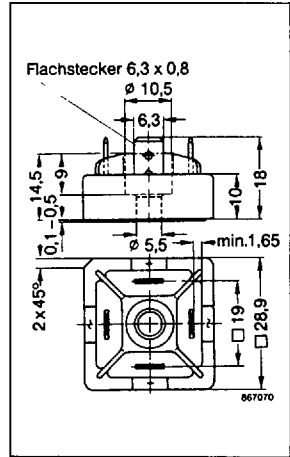
### MAXIMUM RATINGS

Parameter	Symbol	Rating	Unit	
Repetitive Peak Reverse Voltage	-04	$V_{RRM}$	400	V
	-06	$V_{RRM}$	600	V
	-08	$V_{RRM}$	800	V
	-10	$V_{RRM}$	1000	V
	-12	$V_{RRM}$	1200	V
	-14	$V_{RRM}$	1400	V
-16	$V_{RRM}$	1600	V	
Avalanche Power	( $T_{VJ} = T_{VM}$ , $I = 10\mu s$ )	$P_{RSM}$	3.4	kW
Isolation Voltage	(50/60Hz, 1 min)	$V_{ISOL}$	2500	$V_{RMS}$
Average DC Output Current	( $T_C = 85^\circ C$ )	$I_{SAV}$	31	A
RMS Current Limit (2)		$I_{DRMS}$	45	A
Peak Single-Cycle Surge Current, 10ms	( $T_{VJ} = 45^\circ C$ )	$I_{FSM}$	300	A
	( $T_{VJ} = T_{VM}$ )		250	A
Peak Single-Cycle Surge Current, 8.3ms	( $T_{VJ} = 45^\circ C$ )	$I_{FSM}$	315	A
	( $T_{VJ} = T_{VM}$ )		265	A
$I^2 t$ , 10ms	( $T_{VJ} = 45^\circ C$ )	$\int I^2 t$	450	$A^2 s$
	( $T_{VJ} = T_{VM}$ )		312	$A^2 s$
$I^2 t$ , 8.3ms	( $T_{VJ} = 45^\circ C$ )	$\int I^2 t$	420	$A^2 s$
	( $T_{VJ} = T_{VM}$ )		290	$A^2 s$
Operating & Storage Temperature	$T_J$	-40 to +150°C	°C	
Operating & Storage Temperature	$T_{STG}$	-40 to +125°C	°C	
Torque Limit for Mounting Screws (1)	$M_D$	2.5/22	Nm/in-lb	
Weight		150/6	g/oz	

\* IXYS reserves the right to change limits, test conditions, and dimensions without notice

## VBO20

Part Number		$V_{RRM}$	Idev
Normal	Avalanche		
VBO20-04N02		400V	31A
VBO20-06N02		600V	
VBO20-08N02		800V	
VBO20-10N02		1000V	
VBO20-12N02	VBO20-12A02	1200V	
VBO20-14N02	VBO20-14A02	1400V	
VBO20-16N02	VBO20-16A02	1600V	



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VBO20

ELECTRICAL CHARACTERISTICS (per diode)

CHARACTERISTIC	TEST CONDITION	SYMBOL	MAX	UNIT
Reverse Leakage Current	$T_{VJ} = 125^{\circ}\text{C}; V_R = V_{RRM}$	$I_R$	5.0	mA
Forward Voltage Drop	$I_F = 55\text{A}, T_{VJ} = 25^{\circ}\text{C}$	$V_F$	1.6	V
Forward Drop Constants for Power Loss Calculations	$T_{VJ} = T_{VM}$	$V_{T0}$	0.85	V
		$r_F$	14	mΩ

THERMAL CHARACTERISTICS

MODULE	Junction - to - Case	$R_{\theta JC}$	3.0	K/W
	Case - to - Heatsink	$R_{\theta CS}$	0.1	K/W
DIODE	Junction - to - Case	$R_{\theta JC}$	0.75	K/W
	Case - to - Heatsink	$R_{\theta CS}$	0.4	K/W

Note: (1) Recommended mounting torque using an M5 or 10-32 UNF fastener is 1.5-2.0 Nm (13.3-17.7 in-lb)

Power dissipation vs. direct output current and ambient temperature or three-phase, rectangular, output current.

